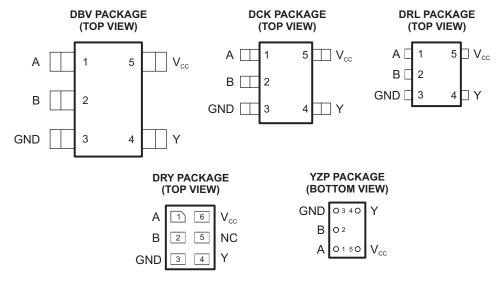


FEATURES

- Available in the Texas Instruments
 NanoStar[™] and NanoFree[™] Packages
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{nd} of 3.6 ns at 3.3 V
- Low Power Consumption, 10-μA Max I_{CC}
- \pm 24-mA Output Drive at 3.3 V

- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



NC – No internal connection
See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

This single 2-input positive-OR gate is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G32 performs the Boolean function $Y = A + B \text{ or } Y = \overline{A \cdot B}$ in positive logic.

NanoStar[™] and NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar, NanoFree are trademarks of Texas Instruments.



ORDERING INFORMATION

| T _A | PACKAGE ⁽¹⁾ | | ORDERABLE PART NUMBER | TOP-SIDE MARKING(2) |
|----------------|--|--------------|-----------------------|---------------------|
| | NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free) | Reel of 3000 | SN74LVC1G32YZPR | CG_ |
| | SON - DRY | Reel of 5000 | SN74LVC1G32DRYR | CG_ |
| | | | SN74LVC1G32DBVR | |
| | SOT (SOT-23) – DBV | Reel of 3000 | SN74LVC1G32DBVRE4 | C22 |
| | | | SN74LVC1G32DBVRG4 | C32_ |
| | | Tube of 250 | SN74LVC1G32DBVT | |
| –40°C to 85°C | | Reel of 3000 | SN74LVC1G32DCKR | |
| | | | SN74LVC1G32DCKRE4 | |
| | SOT (SC-70) – DCK | | SN74LVC1G32DCKRG4 | CG_ |
| | | Tube of 250 | SN74LVC1G32DCKT | |
| | | Tube 01 250 | SN74LVC1G32DCKTE4 | |
| | SOT (SOT 553) DDI | Reel of 4000 | SN74LVC1G32DRLR | CG |
| | SOT (SOT-553) – DRL | Reel of 4000 | SN74LVC1G32DRLRG4 | CG_ |

- Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
 DBV/DCK/DRL/DRY: The actual top-side marking has one additional character that designates the assembly/test site.
- (2) DBV/DCK/DRLY: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free).

FUNCTION TABLE

| INP | OUTPUT | |
|-----|--------|---|
| Α | В | Υ |
| Н | Х | Н |
| Х | Н | Н |
| L | L | L |

LOGIC DIAGRAM (POSITIVE LOGIC)



SN74LVC1G32 SINGLE 2-INPUT POSITIVE-OR GATE

SCES2190-APRIL 1999-REVISED FEBRUARY 2007

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|------------------|---|-----------------------------|------|-----------------------|------|
| V_{CC} | Supply voltage range | | -0.5 | 6.5 | V |
| VI | Input voltage range ⁽²⁾ | | -0.5 | 6.5 | V |
| Vo | Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾ | | -0.5 | 6.5 | V |
| Vo | Voltage range applied to any output in the | he high or low state (2)(3) | -0.5 | V _{CC} + 0.5 | V |
| I _{IK} | Input clamp current | V _I < 0 | | -50 | mA |
| I _{OK} | Output clamp current | V _O < 0 | | -50 | mA |
| Io | Continuous ouput current | | ±50 | mA | |
| | Continuous current through V _{CC} or GND |) | | ±100 | mA |
| | | DBV package | | 206 | |
| | | DCK package | | 252 | |
| θ_{JA} | Package thermal impedance (4) | DRL package | | 142 | °C/W |
| | | DRY package | | 234 | |
| | | YZP package | | 132 | |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

³⁾ The value of V_{CC} is provided in the recommended operating conditions table.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

SN74LVC1G32 SINGLE 2-INPUT POSITIVE-OR GATE

SCES2190-APRIL 1999-REVISED FEBRUARY 2007



Recommended Operating Conditions⁽¹⁾

| | | | MIN | MAX | UNIT | |
|----------------|------------------------------------|--|------------------------|----------------------|------|--|
| ., | Complexed to a co | Operating | 1.65 | 5.5 | V | |
| V_{CC} | Supply voltage | Data retention only | 1.5 | | V | |
| | | V _{CC} = 1.65 V to 1.95 V | 0.65 × V _{CC} | | | |
| ., | High level inner valence | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | | V | |
| V_{IH} | High-level input voltage | V _{CC} = 3 V to 3.6 V | 2 | | V | |
| | | V _{CC} = 4.5 V to 5.5 V | $0.7 \times V_{CC}$ | | | |
| | | V _{CC} = 1.65 V to 1.95 V | | $0.35 \times V_{CC}$ | | |
| V | Low lovel input valtage | V _{CC} = 2.3 V to 2.7 V | | 0.7 | V | |
| V_{IL} | Low-level input voltage | V _{CC} = 3 V to 3.6 V | | 0.8 | V | |
| | | V _{CC} = 4.5 V to 5.5 V | | $0.3 \times V_{CC}$ | | |
| VI | Input voltage | | 0 | 5.5 | V | |
| Vo | Output voltage | | 0 | V_{CC} | V | |
| | | V _{CC} = 1.65 V | | -4 | | |
| | | V _{CC} = 2.3 V | | -8 | | |
| I_{OH} | High-level output current | el output current | | -16 | mA | |
| | | V _{CC} = 3 V | | -24 | | |
| | | V _{CC} = 4.5 V | | -32 | | |
| | | V _{CC} = 1.65 V | | 4 | | |
| | | V _{CC} = 2.3 V | | 8 | | |
| I_{OL} | Low-level output current | V 2V | | 16 | mA | |
| | | V _{CC} = 3 V | | 24 | | |
| | | V _{CC} = 4.5 V | | 32 | | |
| | | V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V | | 20 | | |
| Δt/Δν | Input transition rise or fall rate | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | | 10 | ns/V | |
| | | $V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ | | 5 | | |
| T _A | Operating free-air temperature | · | -40 | 85 | °C | |

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | V _{cc} | MIN TYP(1) | MAX | UNIT | |
|------------------------------|--|-----------------|-----------------------|------|------|--|
| | $I_{OH} = -100 \mu A$ | 1.65 V to 5.5 V | V _{CC} – 0.1 | | | |
| | $I_{OH} = -4 \text{ mA}$ | 1.65 V | 1.2 | | | |
| V | $I_{OH} = -8 \text{ mA}$ | 2.3 V | 1.9 | | V | |
| V _{OH} | $I_{OH} = -16 \text{ mA}$ | 3 V | 2.4 | | V | |
| | $I_{OH} = -24 \text{ mA}$ | 3 V | 2.3 | | | |
| | $I_{OH} = -32 \text{ mA}$ | 4.5 V | 3.8 | | | |
| | I _{OL} = 100 μA | 1.65 V to 5.5 V | | 0.1 | | |
| | I _{OL} = 4 mA | 1.65 V | | 0.45 |).45 | |
| \/ | I _{OL} = 8 mA | 2.3 V | | 0.3 | V | |
| V _{OL} | I _{OL} = 16 mA | 3 V | | 0.4 | V | |
| | I _{OL} = 24 mA | 3 V | 0.55 | | | |
| | I _{OL} = 32 mA | 4.5 V | | 0.55 | | |
| I _I A or B inputs | V _I = 5.5 V or GND | 0 to 5.5 V | | ±5 | μΑ | |
| l _{off} | V_I or $V_O = 5.5 \text{ V}$ | 0 | | ±10 | μΑ | |
| I _{cc} | $V_I = 5.5 \text{ V or GND}, \qquad I_O = 0$ | 1.65 V to 5.5 V | | 10 | μΑ | |
| ΔI_{CC} | One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND | 3 V to 5.5 V | | 500 | μΑ | |
| C _i | $V_I = V_{CC}$ or GND | 3.3 V | 4 | | pF | |

⁽¹⁾ All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = ± 0.1 | | V _{CC} = 1 ± 0.2 | | V _{CC} = ± 0.3 | | V _{CC} = | | UNIT |
|-----------------|-----------------|----------------|----------------------------|-----|------------------------------|-----|----------------------------|-----|-------------------|-----|------|
| | (INPOT) | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| t _{pd} | A or B | Υ | 1.9 | 7.2 | 0.8 | 4.4 | 0.9 | 3.6 | 8.0 | 3.4 | ns |

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 2)

| | PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = ± 0.1 | 1.8 V 5 V | V _{CC} = ± 0.2 | | V _{CC} = ± 0.3 | | V _{CC} = | | UNIT |
|--|-----------------|-----------------|----------------|----------------------------|--------------|----------------------------|-----|----------------------------|-----|-------------------|-----|------|
| | | (INPOT) | (001701) | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| | t _{pd} | A or B | Υ | 2.8 | 8 | 1.2 | 5.5 | 1.1 | 4.5 | 1 | 4 | ns |

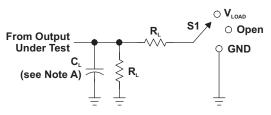
Operating Characteristics

 $T_A = 25^{\circ}C$

| PARAMETER | | TEST | V _{CC} = 1.8 V | V _{CC} = 2.5 V | V _{CC} = 3.3 V | V _{CC} = 5 V | UNIT |
|-----------|-------------------------------|------------|-------------------------|-------------------------|-------------------------|-----------------------|------|
| | FARAMETER | CONDITIONS | TYP | TYP | TYP | TYP | UNII |
| C_{pd} | Power dissipation capacitance | f = 10 MHz | 20 | 20 | 21 | 22 | pF |



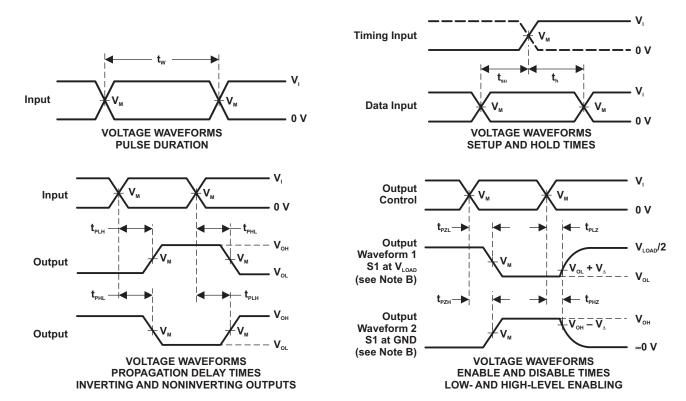
PARAMETER MEASUREMENT INFORMATION



| TEST | S1 |
|---|-------------------|
| t _{PLH} /t _{PHL} | Open |
| t_{PLZ}/t_{PZL} | V _{LOAD} |
| $t_{_{\mathrm{PHZ}}}/t_{_{\mathrm{PZH}}}$ | GND |

LOAD CIRCUIT

| | INI | PUTS | V V | | | - | V, |
|-----------------|-----------------|---------|--------------------|----------------------------------|-------|-------------------------------|--------|
| V _{cc} | V, | t,/t, | V _M | V _M V _{LOAD} | | C _L R _L | |
| 1.8 V ± 0.15 V | V _{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 15 pF | 1 M Ω | 0.15 V |
| 2.5 V ± 0.2 V | V _{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 15 pF | 1 M Ω | 0.15 V |
| 3.3 V ± 0.3 V | 3 V | ≤2.5 ns | 1.5 V | 6 V | 15 pF | 1 M Ω | 0.3 V |
| 5 V ± 0.5 V | V _{cc} | ≤2.5 ns | V _{cc} /2 | 2 × V _{cc} | 15 pF | 1 M Ω | 0.3 V |



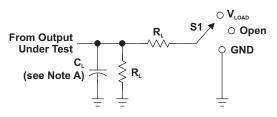
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_o = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and \dot{t}_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



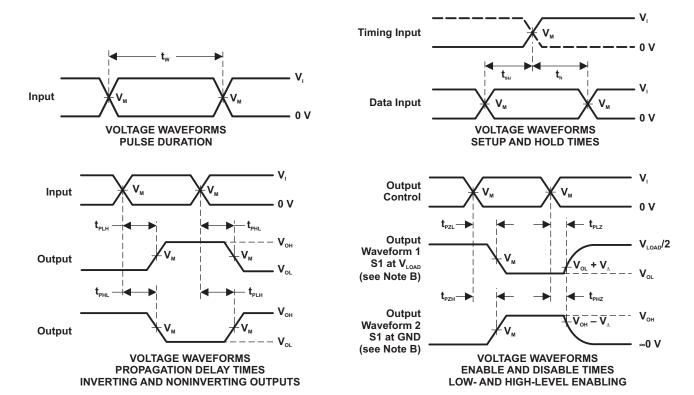
PARAMETER MEASUREMENT INFORMATION (continued)



| TEST | S1 |
|------------------------------------|-------------------|
| t _{PLH} /t _{PHL} | Open |
| t _{PLZ} /t _{PZL} | V _{LOAD} |
| t _{PHZ} /t _{PZH} | GND |

LOAD CIRCUIT

| | INI | PUTS | | v v | | - | W |
|-------------------|-----------------|---------|--------------------|--------------------------|----------------|----------------|----------------|
| V _{cc} | V, | t,/t, | V _M | V _{LOAD} | C _L | R _L | V _Δ |
| 1.8 V ± 0.15 V | V _{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 30 pF | 1 k Ω | 0.15 V |
| 2.5 V ± 0.2 V | V _{cc} | ≤2 ns | V _{cc} /2 | 2 × V _{cc} | 30 pF | 500 Ω | 0.15 V |
| $3.3~V~\pm~0.3~V$ | 3 V | ≤2.5 ns | 1.5 V | 6 V | 50 pF | 500 Ω | 0.3 V |
| 5 V ± 0.5 V | V _{cc} | ≤2.5 ns | V _{cc} /2 | 2 × V _{cc} | 50 pF | 500 Ω | 0.3 V |



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{nd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms







PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | e Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ |
|-------------------|-----------------------|-----------------|--------------------|------|----------------|---------------------------|------------------|------------------------------|
| SN74LVC1G32DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DBVRE4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DBVTE4 | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DBVTG4 | ACTIVE | SOT-23 | DBV | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DCKRE4 | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DCKT | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DCKTE4 | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DCKTG4 | ACTIVE | SC70 | DCK | 5 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DRLR | ACTIVE | SOT | DRL | 5 | 4000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DRLRG4 | ACTIVE | SOT | DRL | 5 | 4000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DRYR | ACTIVE | SON | DRY | 6 | 5000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32DRYRG4 | ACTIVE | SON | DRY | 6 | 5000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM |
| SN74LVC1G32YZPR | ACTIVE | DSBGA | YZP | 5 | 3000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-1-260C-UNLIM |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

18-Sep-2008

retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF SN74LVC1G32:

• Automotive: SN74LVC1G32-Q1

• Enhanced Product: SN74LVC1G32-EP

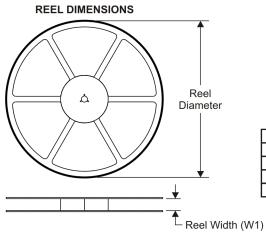
NOTE: Qualified Version Definitions:

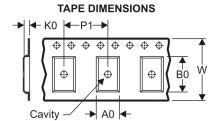
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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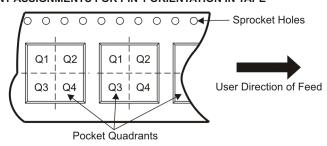
TAPE AND REEL INFORMATION





| | Dimension designed to accommodate the component width |
|----|---|
| | Dimension designed to accommodate the component length |
| | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| All dimensions are nominal | 1 | | | i | П | | | | | | | _ |
|----------------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| SN74LVC1G32DBVR | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 9.2 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DBVT | SOT-23 | DBV | 5 | 250 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 9.2 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 9.2 | 2.24 | 2.34 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DCKT | SC70 | DCK | 5 | 250 | 180.0 | 9.2 | 2.24 | 2.34 | 1.22 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DCKT | SC70 | DCK | 5 | 250 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DRLR | SOT | DRL | 5 | 4000 | 180.0 | 9.2 | 1.78 | 1.78 | 0.69 | 4.0 | 8.0 | Q3 |
| SN74LVC1G32DRYR | SON | DRY | 6 | 5000 | 179.0 | 8.4 | 1.2 | 1.65 | 0.7 | 4.0 | 8.0 | Q1 |
| SN74LVC1G32YZPR | DSBGA | YZP | 5 | 3000 | 180.0 | 8.4 | 1.02 | 1.52 | 0.63 | 4.0 | 8.0 | Q1 |

PACKAGE MATERIALS INFORMATION

www.ti.com 22-Sep-2009



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74LVC1G32DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G32DBVR | SOT-23 | DBV | 5 | 3000 | 205.0 | 200.0 | 33.0 |
| SN74LVC1G32DBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G32DBVT | SOT-23 | DBV | 5 | 250 | 205.0 | 200.0 | 33.0 |
| SN74LVC1G32DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G32DCKR | SC70 | DCK | 5 | 3000 | 205.0 | 200.0 | 33.0 |
| SN74LVC1G32DCKT | SC70 | DCK | 5 | 250 | 205.0 | 200.0 | 33.0 |
| SN74LVC1G32DCKT | SC70 | DCK | 5 | 250 | 180.0 | 180.0 | 18.0 |
| SN74LVC1G32DRLR | SOT | DRL | 5 | 4000 | 202.0 | 201.0 | 28.0 |
| SN74LVC1G32DRYR | SON | DRY | 6 | 5000 | 220.0 | 205.0 | 50.0 |
| SN74LVC1G32YZPR | DSBGA | YZP | 5 | 3000 | 220.0 | 220.0 | 34.0 |

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

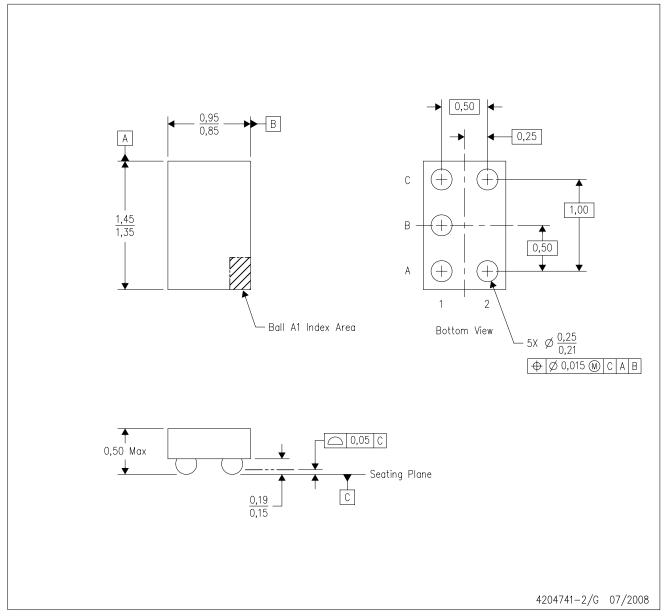
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

 Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY

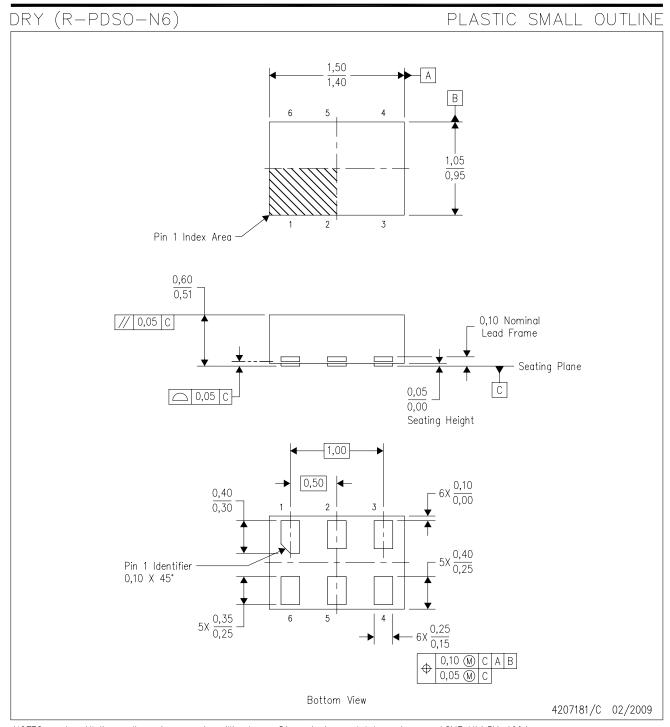


NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree $^{\text{TM}}$ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. SON (Small Outline No-Lead) package configuration.
- D. This package complies to JÉDEC MO-287 variation UFAD.



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